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September 2013

# FGPF15N60UNDF 600 V, 15 A Short Circuit Rated IGBT

#### **Features**

- Short Circuit Rated 10us
- High Current Capability
- High Input Impedance
- · Fast Switching
- · RoHS Compliant

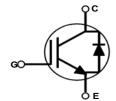
### **General Description**

Using advanced NPT IGBT technology, Fairchild's the NPT IGBTs offer the optimum performance for low-power inverterdriven applications where low-losses and short-circuit ruggedness features are essential, such as sewing machine, CNC, motor control and home appliances.

## **Applications**

• Sewing Machine, CNC, Home Appliances, Motor Control





### **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit	
V <sub>CES</sub>	Collector to Emitter Voltage		600	V	
$V_{GES}$	Gate to Emitter Voltage		± 20	V	
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	30	А	
10	Collector Current	@ T <sub>C</sub> = 100°C	15	A	
I <sub>CM (1)</sub>	Pulsed Collector Current @ T <sub>C</sub> = 25°C		45	Α	
I <sub>F</sub>	Diode Forward Current	$@ T_C = 25^{\circ}C$	15	A	
	Diode Forward Current	$@ T_C = 100^{\circ}C$	7.5	A	
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	42	W	
. Б	Maximum Power Dissipation	$@ T_C = 100^{\circ}C$	17	W	
T <sub>J</sub>	Operating Junction Temperature		-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C	

#### Notes

1: Repetitive rating: Pulse width limited by max. junction temperature

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	3.0	°C/W
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	-	4.9	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)	-	62.5	°C/W

#### Notes:

2: Mountde on 1" square PCB (FR4 or G-10 material)

# **Package Marking and Ordering Information**

Device Marking Device		Package	Reel Size	Tape Width	Quantity
FGPF15N60UNDF FGPF15N60UNDF T		TO-220F	-	-	50ea

# Electrical Characteristics of the IGBT $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V}, I_{C} = 250 \mu\text{A}$	600	-	-	V
I <sub>CES</sub>	Collector Cut-Off Current	$V_{CE} = V_{CES}$ , $V_{GE} = 0$ V	-	-	1	mA
I <sub>GES</sub>	G-E Leakage Current	$V_{GE} = V_{GES}$ , $V_{CE} = 0 V$	-	-	±10	μΑ
On Charac	teristics					
V <sub>GE(th)</sub>	G-E Threshold Voltage	$I_C = 15 \text{ mA}, V_{CE} = V_{GE}$	5.5	6.8	8.5	V
		I <sub>C</sub> = 15 A, V <sub>GE</sub> = 15 V	-	2.2	2.7	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	I <sub>C</sub> = 15 A, V <sub>GE</sub> = 15 V, T <sub>C</sub> = 125°C	-	2.7	-	V
Dynamic C	haracteristics			1		
C <sub>ies</sub>	Input Capacitance		-	619	-	pF
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$	-	80	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1MHz	-	24	-	pF
Switching	Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time		-	9.3	-	ns
t <sub>r</sub>	Rise Time		-	9.8	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 15 \text{ A},$	-	54.8	-	ns
t <sub>f</sub>	Fall Time	$R_G = 10 \Omega, V_{GE} = 15 V,$	-	9.9	12.8	ns
E <sub>on</sub>	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 25°C	-	0.37	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.067	-	mJ
E <sub>ts</sub>	Total Switching Loss		-	0.44	-	mJ
t <sub>d(on)</sub>	Turn-On Delay Time		-	8.9	-	ns
t <sub>r</sub>	Rise Time		- /	9.9	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 15 \text{ A},$	-	56.6	- /	ns
t <sub>f</sub>	Fall Time	$R_G = 10 \Omega$ , $V_{GE} = 15 V$ , Inductive Load, $T_C = 125^{\circ}C$	-	13.2	- ,,/	ns
E <sub>on</sub>	Turn-On Switching Loss		-	0.54	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.11	-	mJ
E <sub>ts</sub>	Total Switching Loss		-	0.65	- /	mJ
T <sub>sc</sub>	Short Circuit Withstand Time	$V_{CC} = 350 \text{ V},$ $R_G = 100 \Omega, V_{GE} = 15 \text{ V},$ $T_C = 150^{\circ}\text{C}$	10	-	-	μs

# Electrical Characteristics of the IGBT $T_C = 25^{\circ}\text{C}$ unless otherwise noted

$Q_g$	Total Gate Charge		-	43	-	nC
$Q_{ge}$	Gate to Emitter Charge	$V_{CE} = 400 \text{ V}, I_{C} = 15 \text{ A},$ $V_{GE} = 15 \text{ V}$	-	6	-	nC
Q <sub>qc</sub>	Gate to Collector Charge	VGE = 10 V	-	26	-	nC

# Electrical Characteristics of the Diode $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditio	ns	Min.	Тур.	Max	Unit
V <sub>FM</sub>	Y <sub>FM</sub> Diode Forward Voltage	I <sub>E</sub> = IO A	$T_C = 25^{\circ}C$	-	1.6	2.2	V
VFM L			T <sub>C</sub> = 125°C	-	1.5	-	
t <sub>rr</sub>	Diode Reverse Recovery Time	-I <sub>F</sub> =15 A, dI <sub>F</sub> /dt = 200 A/μs	$T_C = 25^{\circ}C$	-	82.4		ns
YIT .			T <sub>C</sub> = 125°C	-	142	-	110
Q <sub>rr</sub>	Diode Reverse Recovery Charge	η - 10 Λ, αιρ/αι - 200 Λ/μο	$T_C = 25^{\circ}C$	-	213	-	nC
α <sub>II</sub>	Blood Noveled Nedevely Charge		T <sub>C</sub> = 125°C	-	541	-	1.0

Figure 1. Typical Output Characteristics

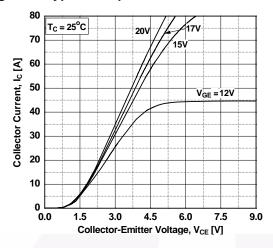


Figure 3. Typical Saturation Voltage Characteristics

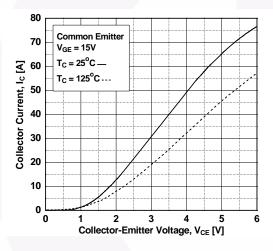
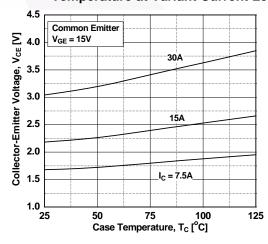
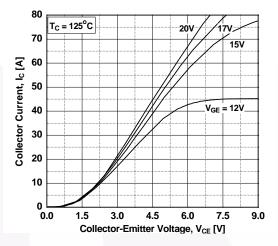


Figure 5. Saturation Voltage vs. Case

Temperature at Variant Current Level



**Figure 2. Typical Output Characteristics** 



**Figure 4. Transfer Characteristics** 

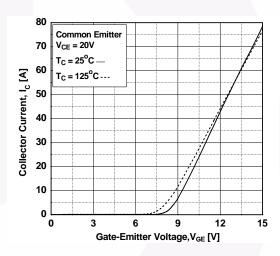


Figure 6. Saturation Voltage vs. V<sub>GE</sub>

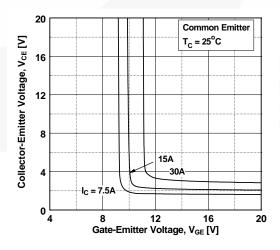


Figure 7. Saturation Voltage vs. V<sub>GE</sub>

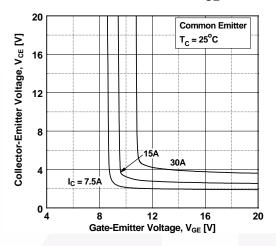


Figure 9. Gate charge Characteristics

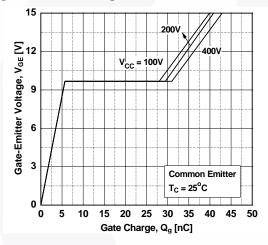
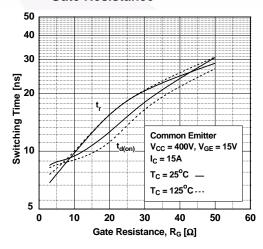


Figure 11. Turn-on Characteristics vs.
Gate Resistance



**Figure 8. Capacitance Characteristics** 

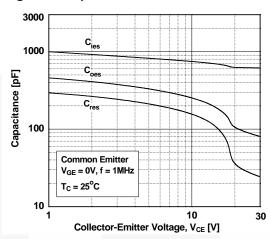


Figure 10. SOA Characteristics

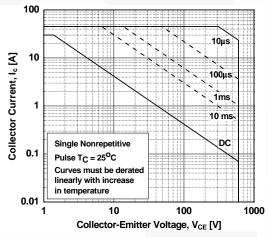


Figure 12. Turn-off Characteristics vs.
Gate Resistance

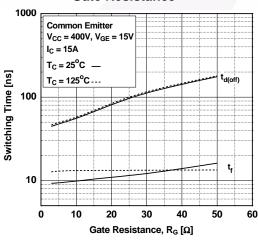


Figure 13. Turn-on Characteristics vs. Collector Current

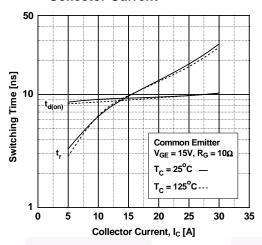


Figure 15. Switching Loss vs.

Gate Resistance

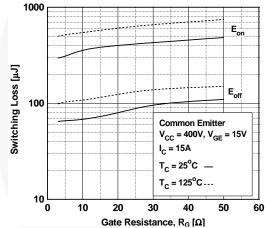


Figure 17. Turn off Switching SOA Characteristics

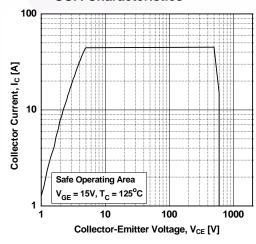


Figure 14. Turn-off Characteristics vs. Collector Current

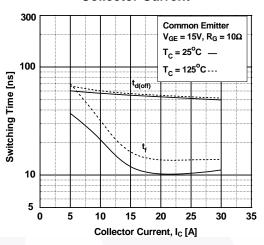


Figure 16. Switching Loss vs Collector Current

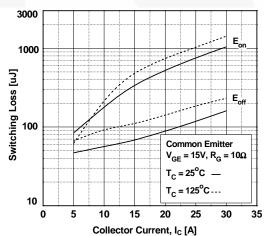


Figure 18. Forward Characteristics

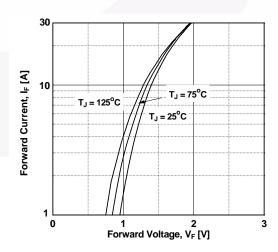
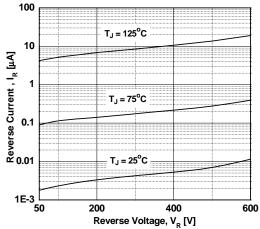


Figure 19. Reverse Current



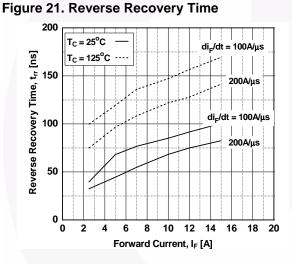


Figure 20. Stored Charge

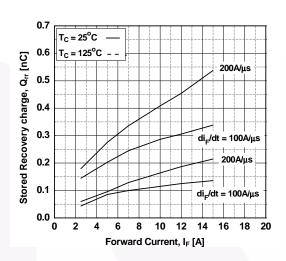
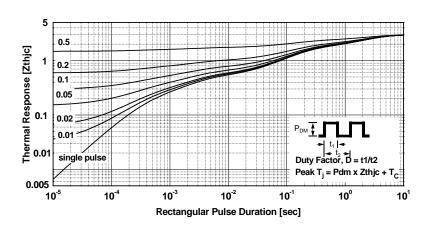


Figure 22. Transient Thermal Impedance of IGBT



### **Mechanical Dimensions**

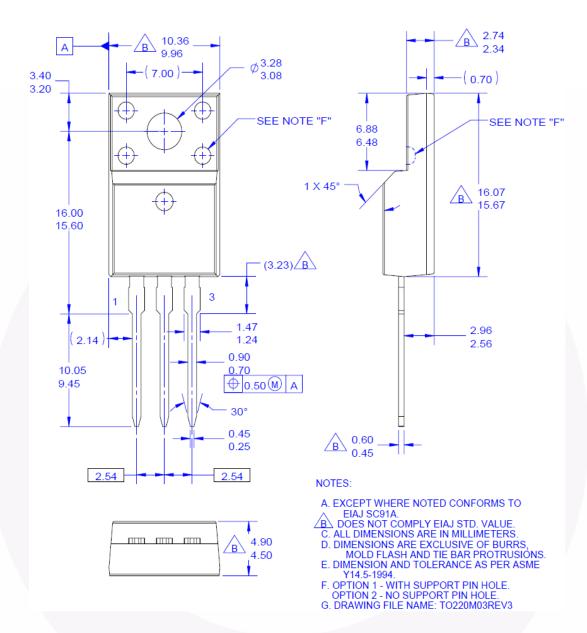


Figure 23. TO-220F 3L - TO220, MOLDED, 3LD, FULL PACK, EIAJ SC91, STRAIGHT LEAD

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Dimensions in Millimeters





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